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SemiNex delivers the highest available power at infrared wavelengths between 12xx and 19xx nm. When necessary wavelengths between 12xx and 19xx nm. When necessary we will further optimize the design of our InP laser chips to meet our customers' specific optical and electrical performance needs. Diodes, bars and packages are tested to meet customer and market performance demands. Typical results and packaging options are shown. Contact SemiNex for additional details or to discuss your specific requirements. requirements.



TO-9 Packaged Laser Diode

High Power Single-Mode and Multi-Mode SemiNex Lasers

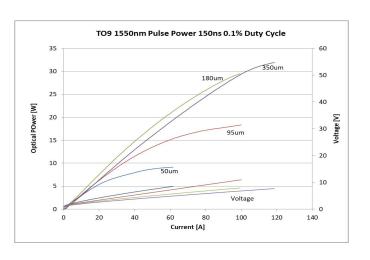
12xx to 19xx nm

Custom Wavelengths Available Lensed Options Available

- ApplicationsOEM MedicalProfessional Medical
- LiDARMilitary / AerospaceIllumination

Features

- Cost effective
- High Output Power
- High Dynamic Range
- High Efficiency
- Standard Low Cost Package



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Pulsed* TO9



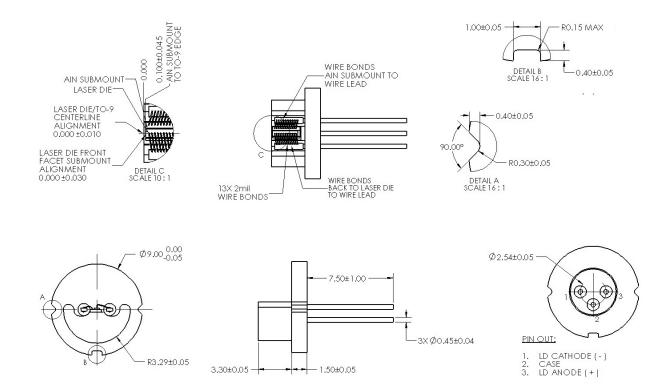
	Symbol	TO9-148	Units
Optical			
Wavelength	$\lambda_{_{ m C}}$	1565	nm (±20)
Output Power (<10ns)	P∘	40.00	watts (±10%)
Output Power (150ns)	P∘	24.00	watts (±10%)
Chip Cavity Length	CL	2500	μm
No. of Junctions		1	
Emitter Width	W	180	μm
Emitter Height	Н	1	μm
Spectral Width	δλ	15	nm 3dB
Slope Efficiency	η∘	0.25	W/A
Fast Axis Div.*	Θ_perp	28	deg FWHM
Slow Axis Div.	Θ_parallel	10	deg FWHM
Electrical			
Power Conversion Eff.	η	3	%
Operating Current (<10ns)	I _{op}	160	A
Operating Current (150ns)	I _{op}	80	A
Threshold Current	I _{th}	1	A
Operating Voltage	V_{op}	9.5	V
Mechanical	<u> </u>		
Weight		1.5	g
Operating Temp.**		-40 to 60	°C
Storage Temp.		-40 to 80	°C

Specified values are rated at a constant heat sink temperature of 20°C.

**Specified operating conditions are based on 20C heat sink temperature. High temperature operation will reduce performance and MTTF.

Unless otherwise indicated all values are nominal.

Uncapped TO9 specifications assume heatsinking underneath laser of the control of the contr



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